

60 V, P-channel Trench MOSFET 21 January 2021

1. General description

P-channel enhancement mode MOSFET in an LFPAK56 (Power SO8) Surface-Mounted Device (SMD) plastic package using Trench MOSFET technology.

This product has been designed and qualified to AEC-Q101 standard for use in high-performance automotive applications such as reverse battery protection.

2. Features and benefits

- High thermal power dissipation capability
- Suitable for thermally demanding environments due to 175 °C rating •
- Trench MOSFET technology •
- AEC-Q101 qualified

3. Applications

- Reverse battery protection
- Power management
- High-side load switch
- Motor drive

4. Quick reference data

Table 1. Quid	ck reference data						
Symbol	Parameter	Conditions		Min	Тур	Мах	Unit
V _{DS}	drain-source voltage	T _j = 25 °C		-	-	-60	V
V _{GS}	gate-source voltage		[1]	-20	-	20	V
I _D	drain current	V _{GS} = -10 V; T _{mb} = 25 °C		-	-	-30	А
P _{tot}	total power dissipation	T _{mb} = 25 °C		-	-	110	W
Static chara	cteristics						
R _{DSon}	drain-source on-state resistance	V _{GS} = -10 V; I _D = -7 A; T _j = 25 °C		-	26	33	mΩ

[1] V_{GS} = -20 V/+5 V according AEC-Q101 at T_j = 175 °C; V_{GS} = -20 V/+20 V according AEC-Q101 at T_j = 150 °C

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5. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	S	source	mb	D
2	S	source		
3	S	source	a	G_(Imp¥)
4	G	gate		s s
mb	D	mounting base; connected to drain	LFPAK56; Power- SO8 (SOT669)	017aaa094

6. Ordering information

Table 3. Ordering information							
Type number	Package	age					
	Name	Description	Version				
BUK6Y33-60P	LFPAK56; Power-SO8	plastic, single-ended surface-mounted package; 4 terminals	SOT669				

7. Marking

Table 4. Marking codes					
Type number	Marking code				
BUK6Y33-60P	6Y3360P				

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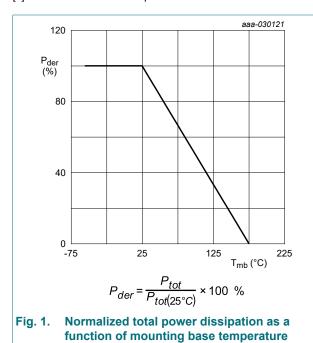
8. Limiting values

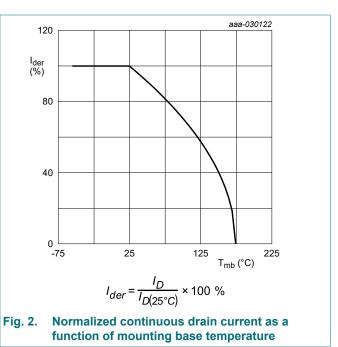
Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

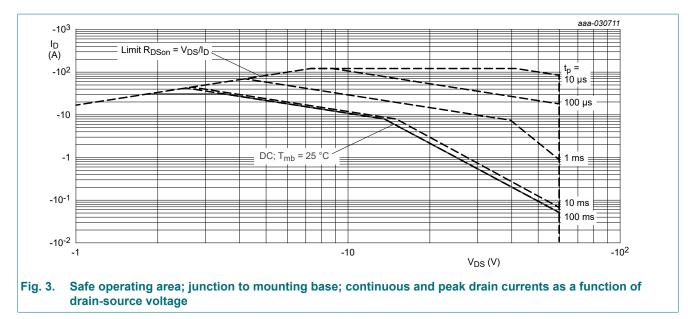
Symbol	Parameter	Conditions		Min	Max	Unit
V _{DS}	drain-source voltage	T _j = 25 °C		-	-60	V
V _{GS}	gate-source voltage		[1]	-20	20	V
I _D	drain current	V _{GS} = -10 V; T _{mb} = 25 °C		-	-30	А
		V _{GS} = -10 V; T _{mb} = 100 °C		-	-21	А
I _{DM}	peak drain current	single pulse; $t_p \le 10 \ \mu$ s; $T_{mb} = 25 \ ^{\circ}C$		-	-120	А
P _{tot}	total power dissipation	T _{mb} = 25 °C		-	110	W
Tj	junction temperature			-55	175	°C
T _{amb}	ambient temperature			-55	175	°C
T _{stg}	storage temperature			-65	175	°C
Source-drai	in diode				-	
Is	source current	T _{mb} = 25 °C		-	-30	А
I _{SM}	peak source current	single pulse; $t_p \le 10 \ \mu$ s; $T_{mb} = 25 \ ^{\circ}C$		-	-120	А
ESD maxim	num rating					
V _{ESD}	electrostatic discharge voltage	НВМ	[2]	-	1000	V
Avalanche i	ruggedness					
E _{DS(AL)S}	non-repetitive drain- source avalanche energy	T _{j(init)} = 25 °C; I _D = -2.8 A; DUT in v avalanche (unclamped)		-	85	mJ

[1] V_{GS} = -20 V/+5 V according AEC-Q101 at T_j = 175 °C; V_{GS} = -20 V/+20 V according AEC-Q101 at T_j = 150 °C [2] Measured between all pins.





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9. Thermal characteristics

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
R _{th(j-mb)}	thermal resistance from junction to mounting base			-	1.1	1.4	K/W
10					é	aa-031187	
10 Z _{th(j-mb)} (K/W)							
1 =0.7 =0.3	0.50						
10-1	0.10						
10 ⁻²	01 0.02 10-4	10-3	10-2				
10-3	10-4	10-2	10-2	10 ⁻¹	t _p (s)	1	

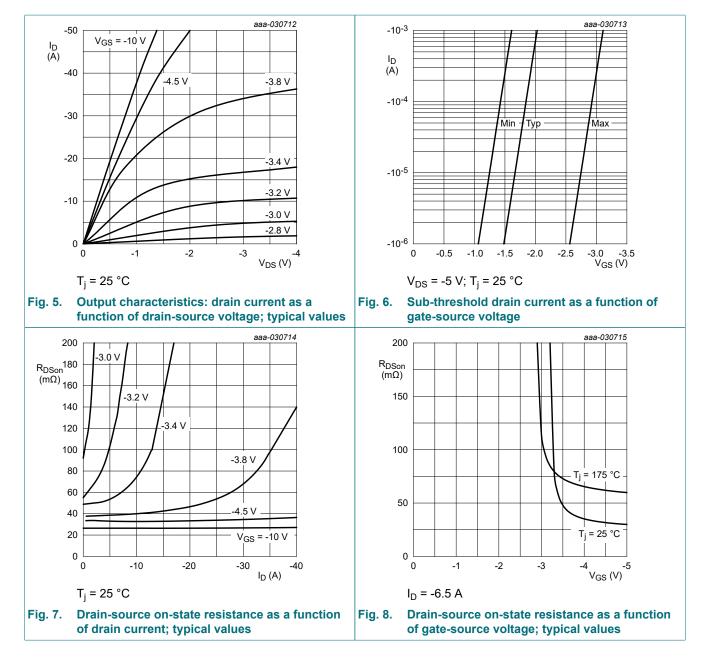
Table 6. Thermal characteristics

BUK6Y33-60P

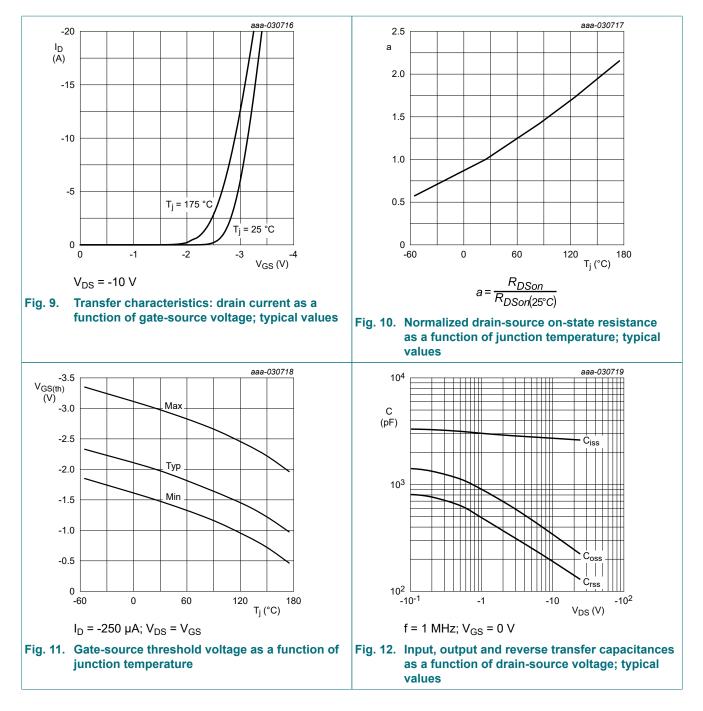
10. Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static chara	octeristics					
V _{(BR)DSS}	drain-source breakdown voltage	I _D = -250 μA; V _{GS} = 0 V; T _j = 25 °C	-60	-	-	V
V _{GSth}	gate-source threshold voltage	I _D = -250 μA; V _{DS} =V _{GS} ; T _j = 25 °C	-1.5	-2	-3	V
I _{DSS}	drain leakage current	V _{DS} = -60 V; V _{GS} = 0 V; T _j = 25 °C	-	-	-1	μA
		V _{DS} = -60 V; V _{GS} = 0 V; T _j = 125 °C	-	-	-10	μA
I _{GSS}	gate leakage current	V _{GS} = -20 V; V _{DS} = 0 V; T _j = 25 °C	-	-	-100	nA
		V _{GS} = 20 V; V _{DS} = 0 V; T _j = 25 °C	-	-	100	nA
R _{DSon}	drain-source on-state	V _{GS} = -10 V; I _D = -7 A; T _j = 25 °C	-	26	33	mΩ
re	resistance	V _{GS} = -10 V; I _D = -7 A; T _j = 175 °C	-	55	69	mΩ
		V _{GS} = -4.5 V; I _D = -6.7 A; T _j = 25 °C	-	30	36	mΩ
9 _{fs}	forward transconductance	V _{DS} = -10 V; I _D = -4.8 A; T _j = 25 °C	-	99	-	S
R _G	gate resistance	f = 1 MHz	-	6.1	-	Ω
Dynamic ch	aracteristics					
Q _{G(tot)}	total gate charge	V_{DS} = -30 V; I _D = -7 A; V _{GS} = -10 V;	-	46	69	nC
Q _{GS}	gate-source charge	T _j = 25 °C	-	7.3	-	nC
Q _{GD}	gate-drain charge		-	9.4	-	nC
C _{iss}	input capacitance	V _{DS} = -30 V; f = 1 MHz; V _{GS} = 0 V;	-	2590	-	pF
C _{oss}	output capacitance	T _j = 25 °C	-	202	-	pF
C _{rss}	reverse transfer capacitance		-	118	-	pF
t _{d(on)}	turn-on delay time	V _{DS} = -30 V; I _D = -7 A; V _{GS} = -10 V;	-	9	-	ns
t _r	rise time	$R_{G(ext)} = 6 \Omega; T_j = 25 °C$	-	16	-	ns
t _{d(off)}	turn-off delay time		-	81	-	ns
t _f	fall time		-	310	-	ns
Source-drai	n diode					
V _{SD}	source-drain voltage	I _S = -30 A; V _{GS} = 0 V; T _j = 25 °C	-	-0.7	-1.2	V
t _{rr}	reverse recovery time	I _S = -30 A; dI _S /dt = 100 A/μs;	-	32	-	ns
Q _r	recovered charge	V _{GS} = -10 V; V _{DS} = -30 V; T _j = 25 °C	-	18	-	nC

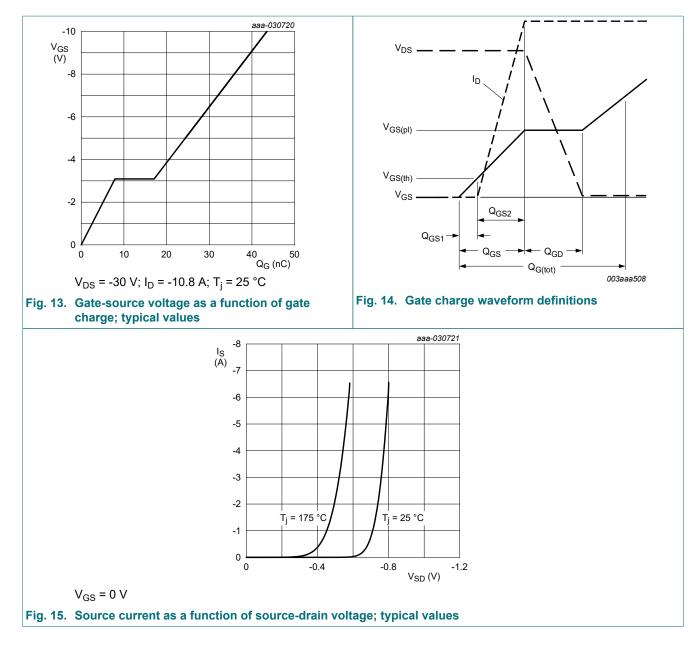
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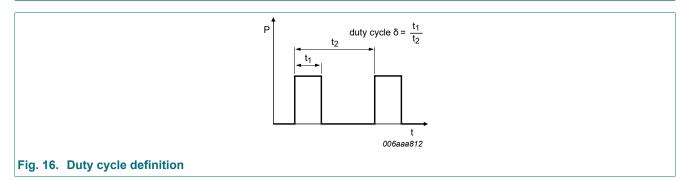


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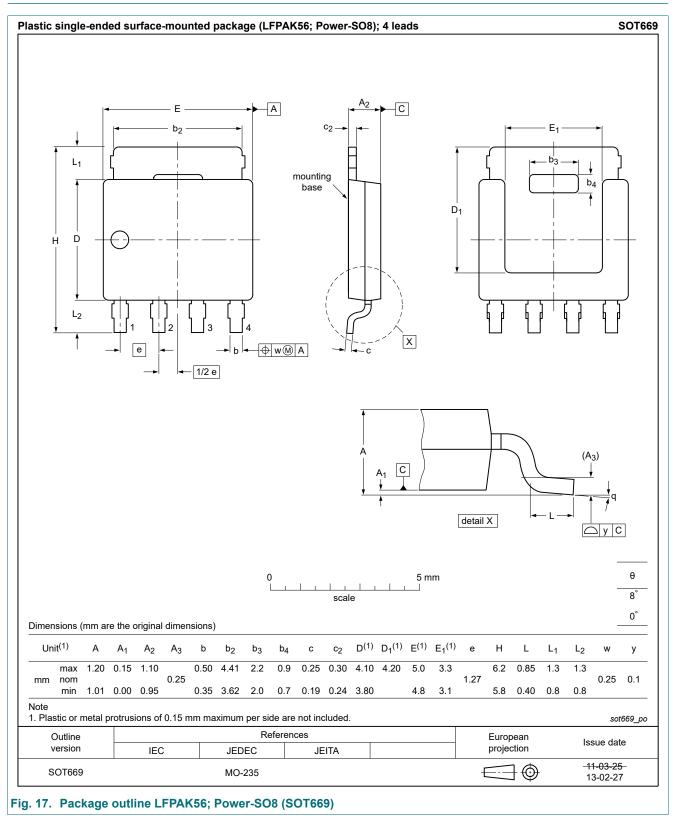
11. Test information



Quality information

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard *Q101* - *Stress test qualification for discrete semiconductors*, and is suitable for use in automotive applications.

12. Package outline



13. Revision history

Data sheet ID	Release date	Data sheet status	Change notice	Supersedes				
BUK6Y33-60P v.3	20210121	Product data sheet	-	BUK6Y33-60P v.2				
Modifications:		Chapter "Characteristics": Typo correction at parameter t _f . Correction of the conditions for the source-drain diode parameters V _{SD} , t _{rr} , Q _r .						
BUK6Y33-60P v.2	20200318	Product data sheet	-	BUK6Y33-60P v.1				
BUK6Y33-60P v.1	20200316	Product data sheet	_	-				

14. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

 Please consult the most recently issued document before initiating or completing a design.

- [2] The term 'short data sheet' is explained in section "Definitions".
- [3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the internet at <u>https://www.nexperia.com</u>.

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